

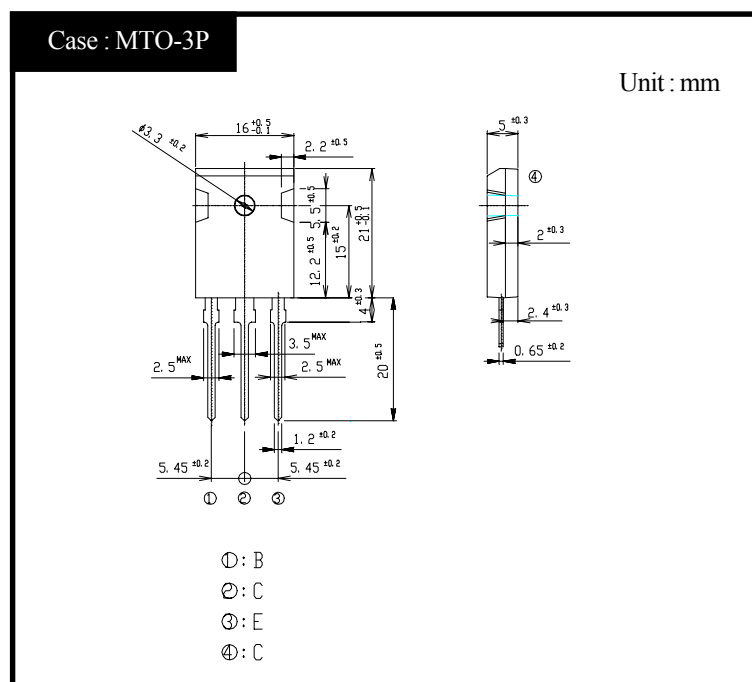
SHINDENGEN

Switching Power Transistor

HFX Series

2SC4237
(T10W80HFX)**10A NPN**

OUTLINE DIMENSIONS



RATINGS

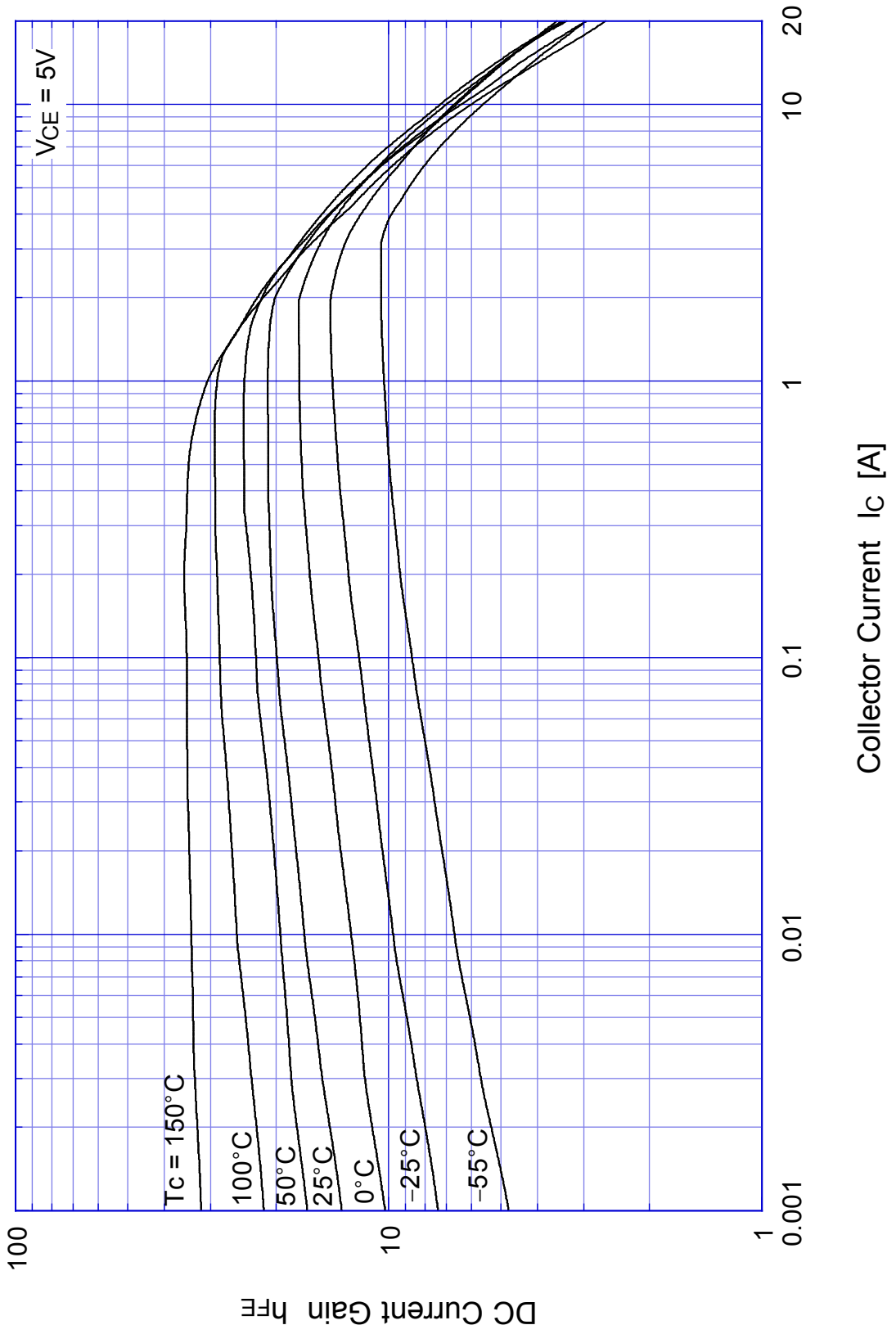
● Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55~150	°C
Junction Temperature	T_j		150	°C
Collector to Base Voltage	V_{CBO}		1200	V
Collector to Emitter Voltage	V_{CEO}		800	V
Emitter to Base Voltage	V_{EBO}		7	V
Collector Current DC	I_C		10	A
Collector Current Peak	I_{CP}		20	
Base Current DC	I_B		4	A
Base Current Peak	I_{BP}		8	
Total Transistor Dissipation	P_T	$T_c = 25^\circ\text{C}$	150	W
Mounting Torque	TOR	(Recommended torque : 0.5N·m)	0.8	N·m

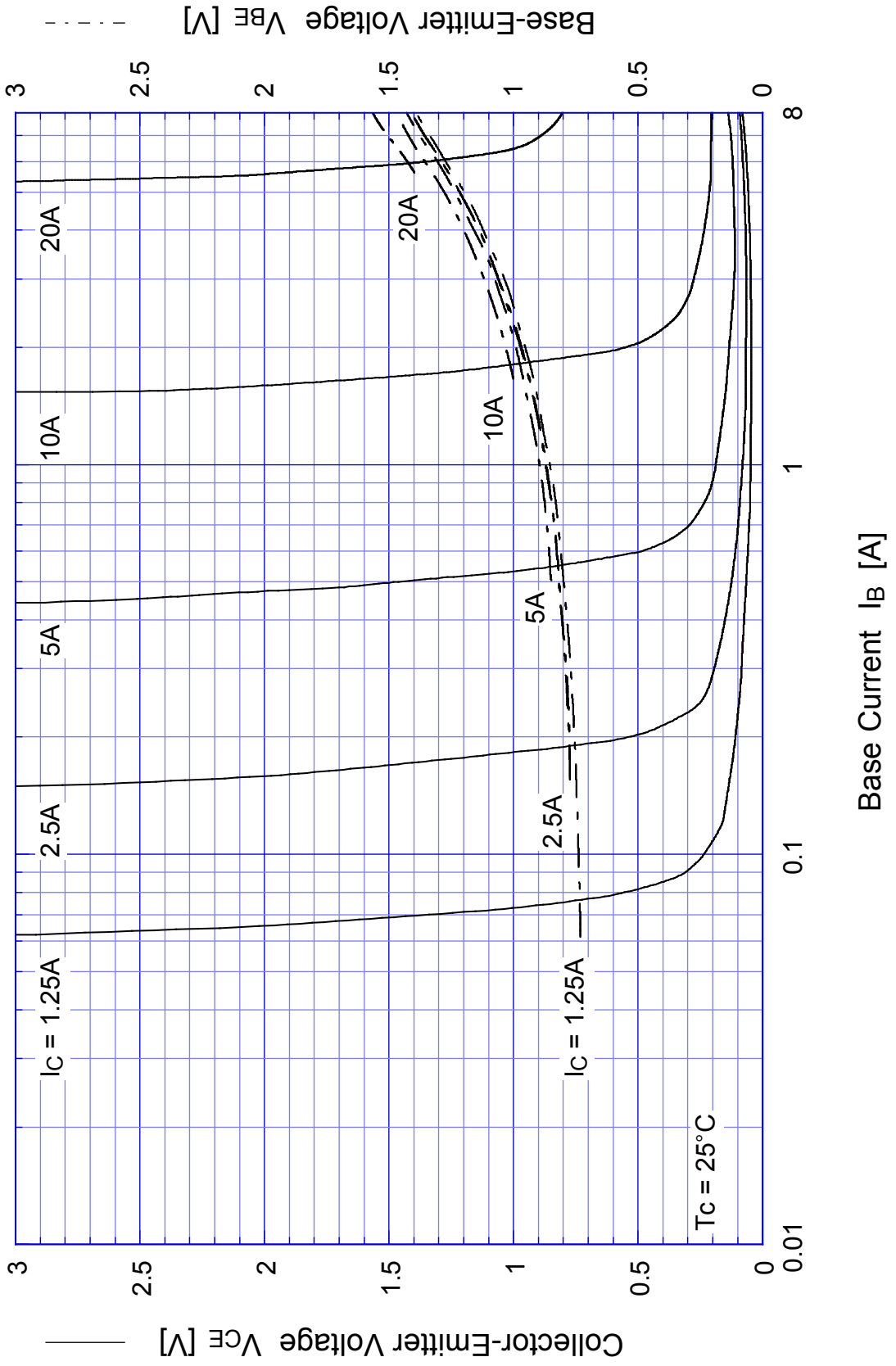
● Electrical Characteristics ($T_c=25^\circ\text{C}$)

Item	Symbol	Conditions	Ratings	Unit
Collector to Emitter Sustaining Voltage	$V_{CEO(sus)}$	$I_C = 0.2A$	Min 800	V
Collector Cutoff Current	I_{CBO}	At rated Voltage	Max 0.1	mA
	I_{CEO}		Max 0.1	
Emitter Cutoff Current	I_{EBO}	At rated Voltage	Max 0.1	mA
DC Current Gain	h_{FE}	$V_{CE} = 5V, I_C = 5A$	Min 8	
	h_{FEL}	$V_{CE} = 5V, I_C = 1mA$	Min 5	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 5A$	Max 1.0	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_B = 1A$	Max 1.5	V
Thermal Resistance	θ_{jc}	Junction to case	Max 0.83	°C/W
Transition Frequency	f_T	$V_{CE} = 10V, I_C = 1A$	TYP 8	MHz
Turn on Time	t_{on}	$I_C = 5A$	Max 0.5	μs
Storage Time	t_s	$I_{B1} = 1A, I_{B2} = 2A$	Max 3.5	
Fall Time	t_f	$R_L = 50\Omega, V_{BB2} = 4V$	Max 0.3	

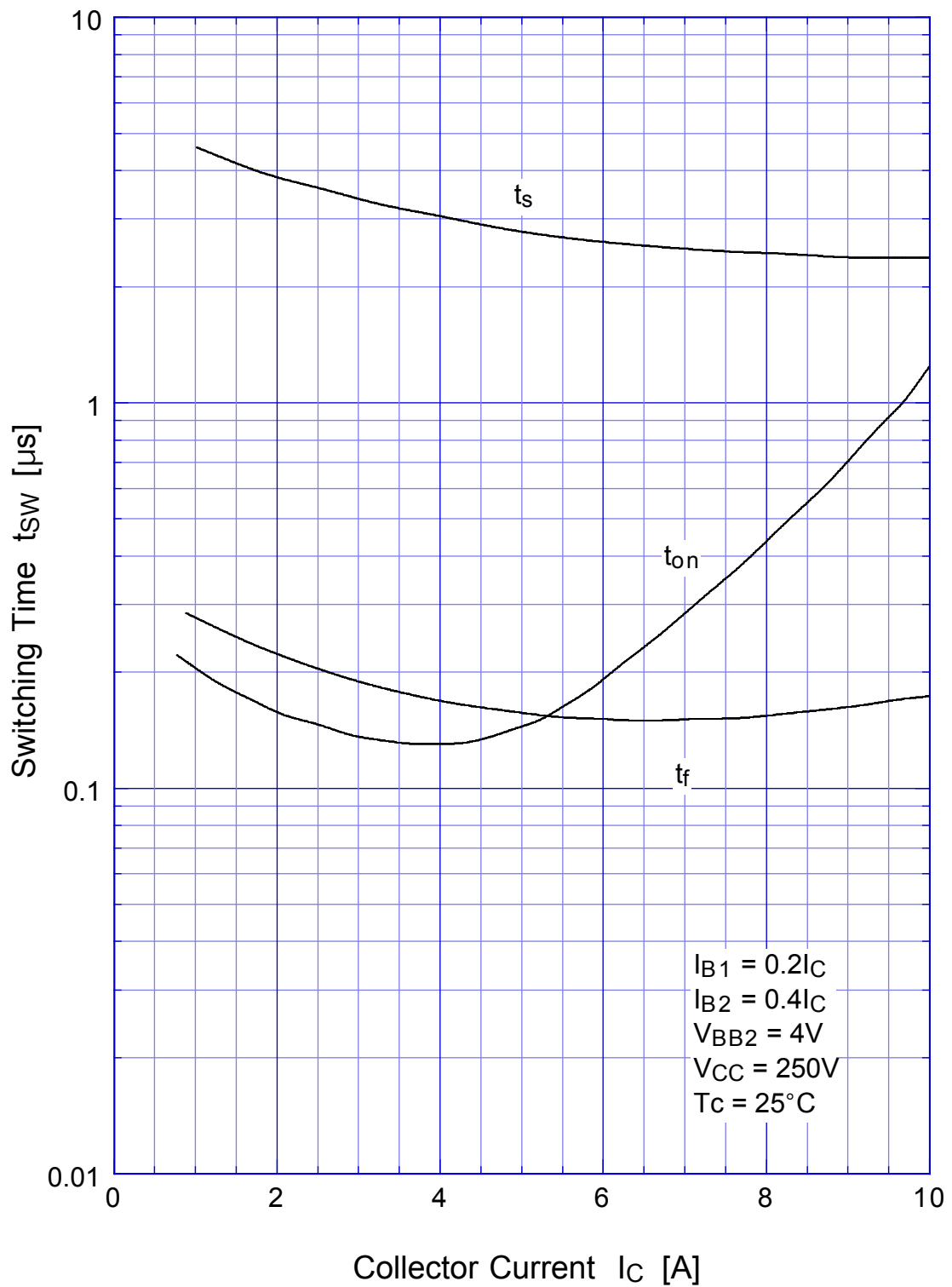
2SC4237 $h_{FE} - I_C$



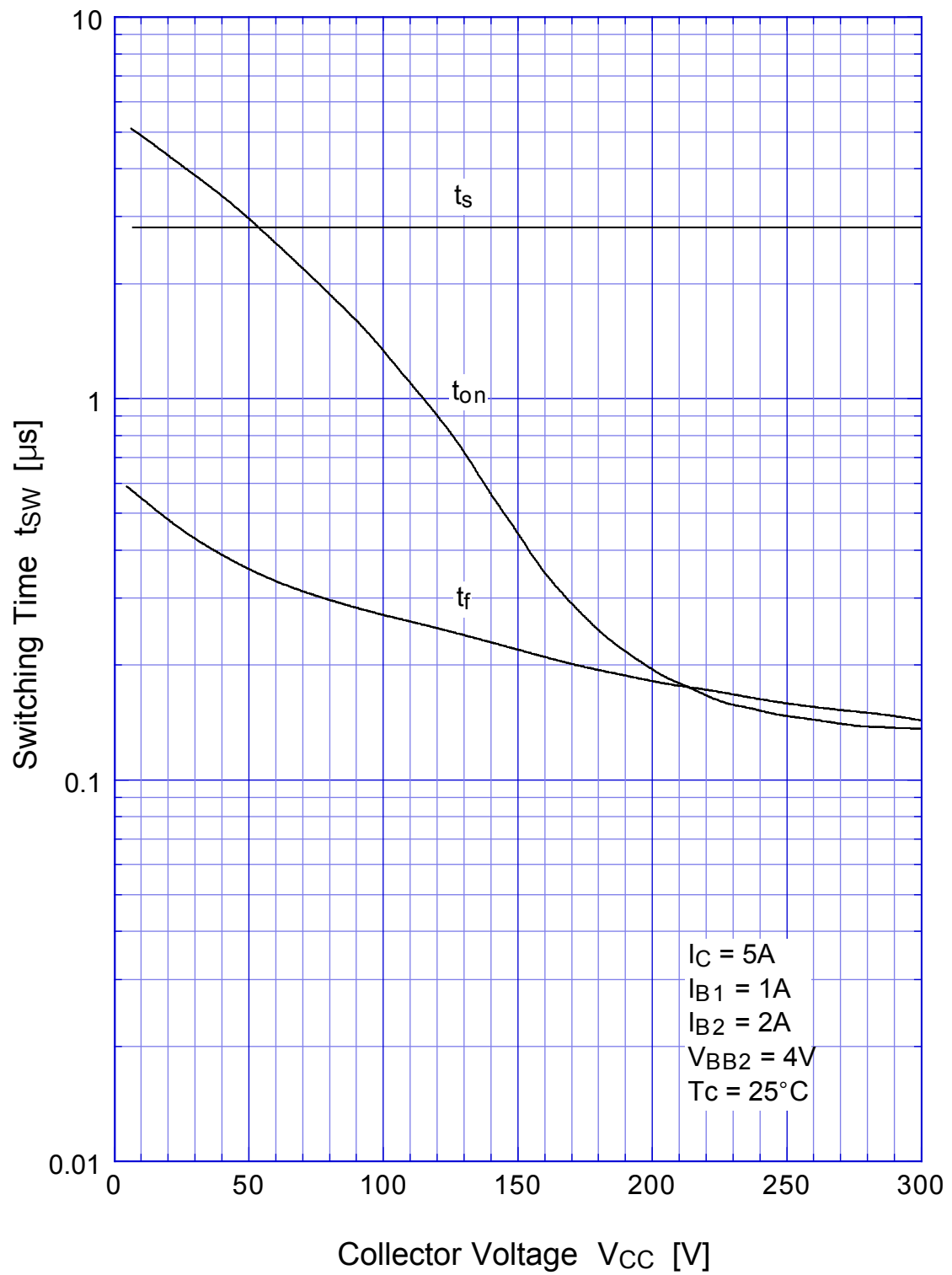
2SC4237 Saturation Voltage



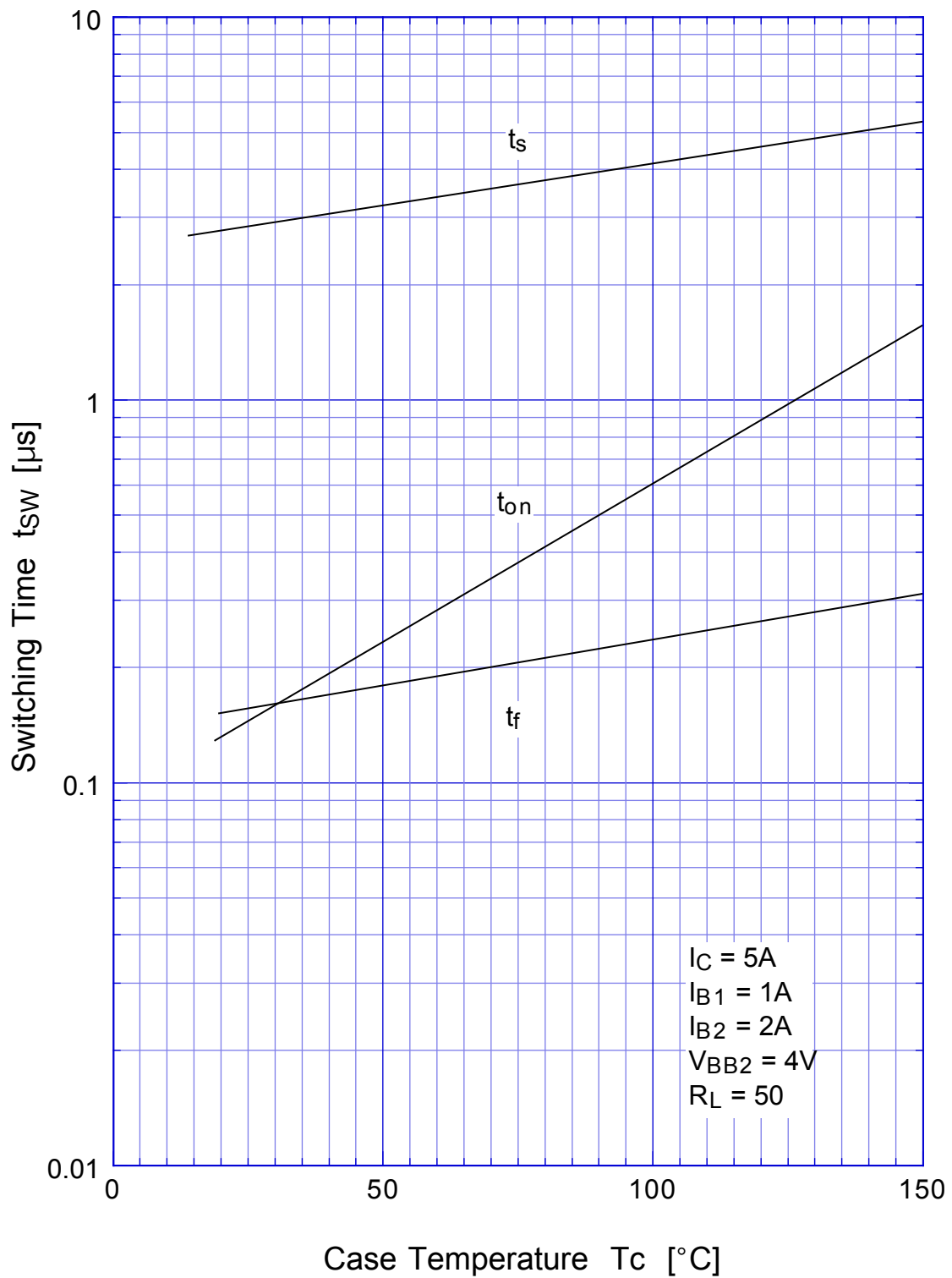
2SC4237 Switching Time - I_C



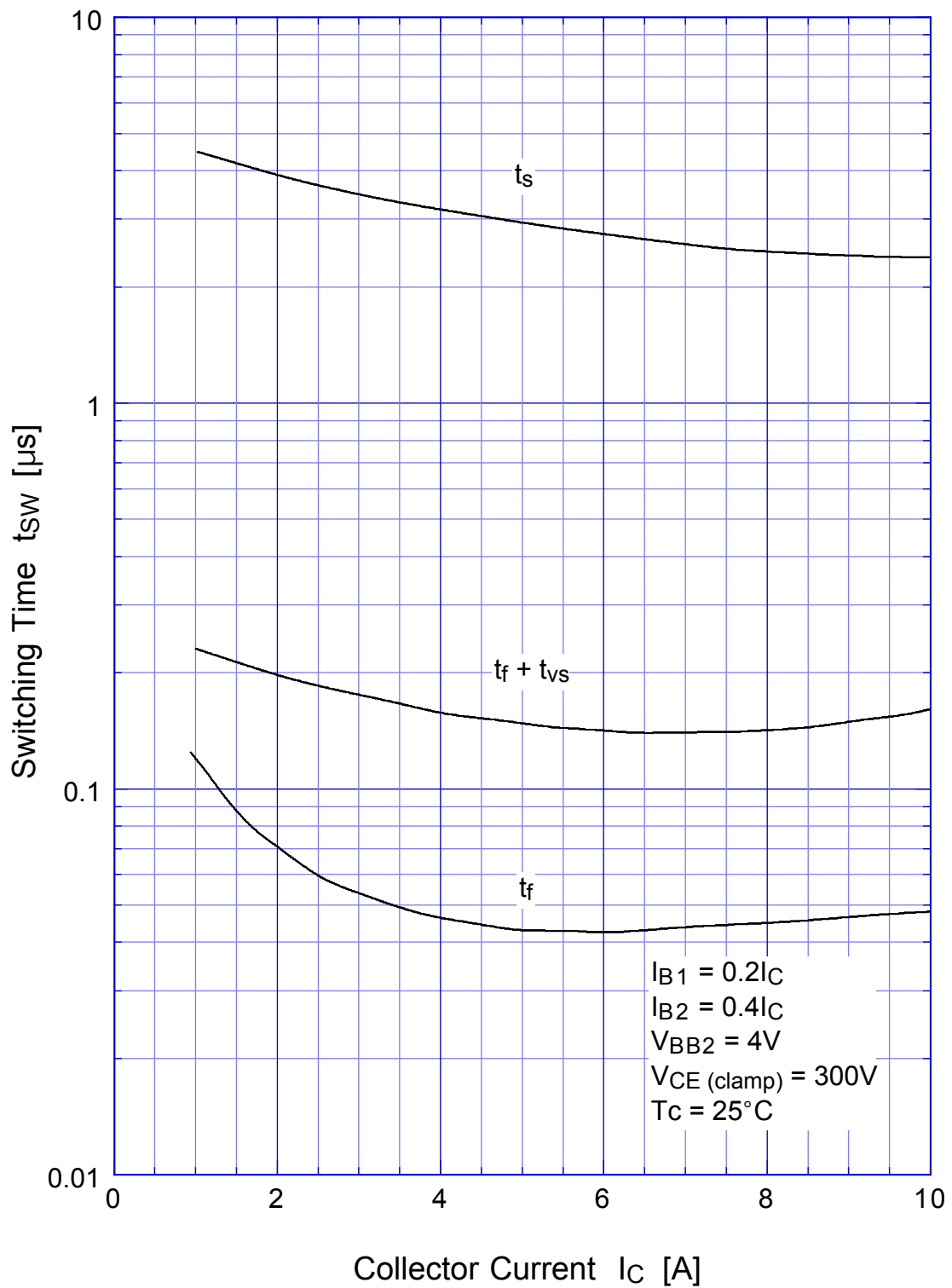
2SC4237 Switching Time - V_{CC}



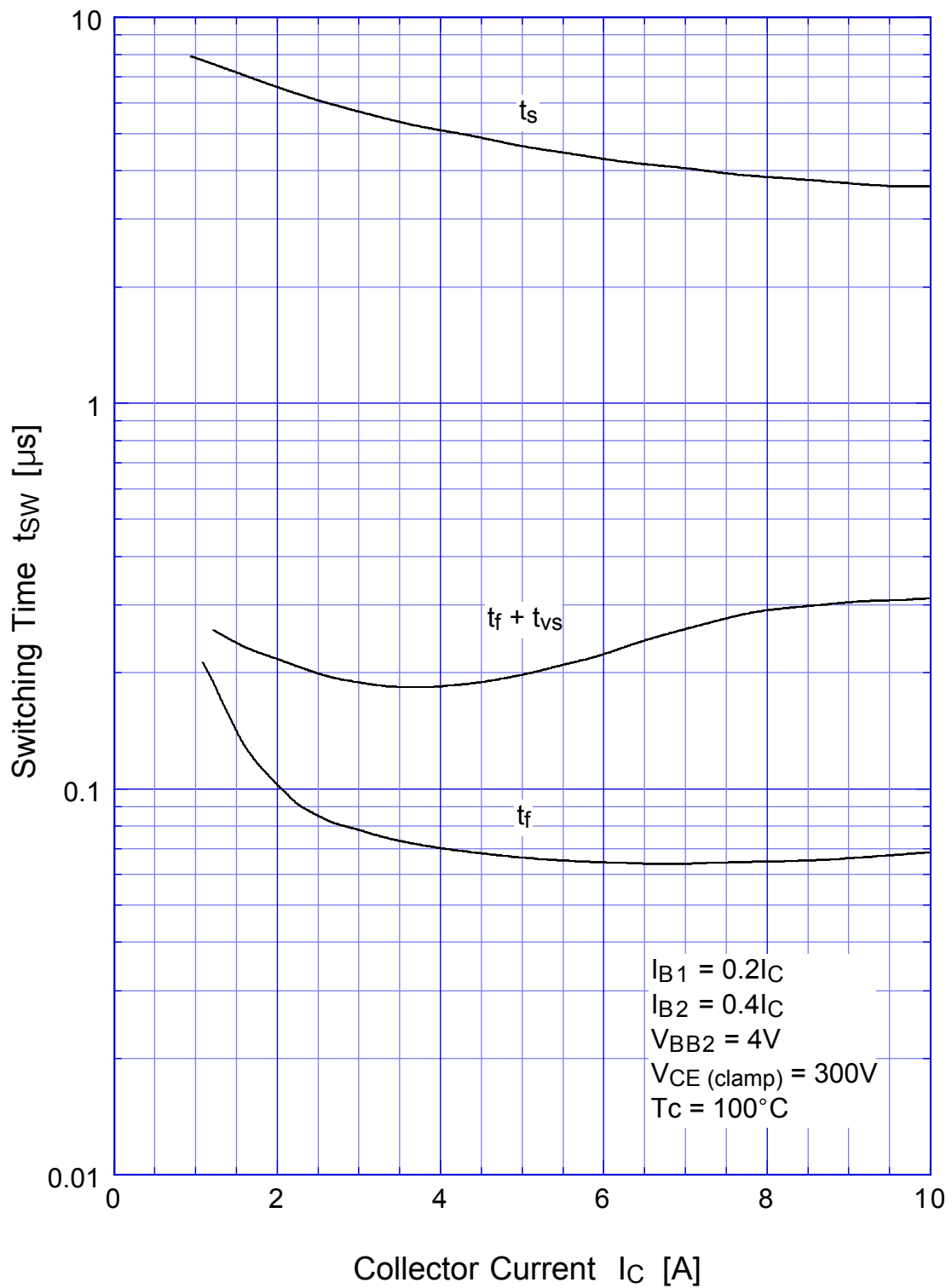
2SC4237 Switching Time - Tc



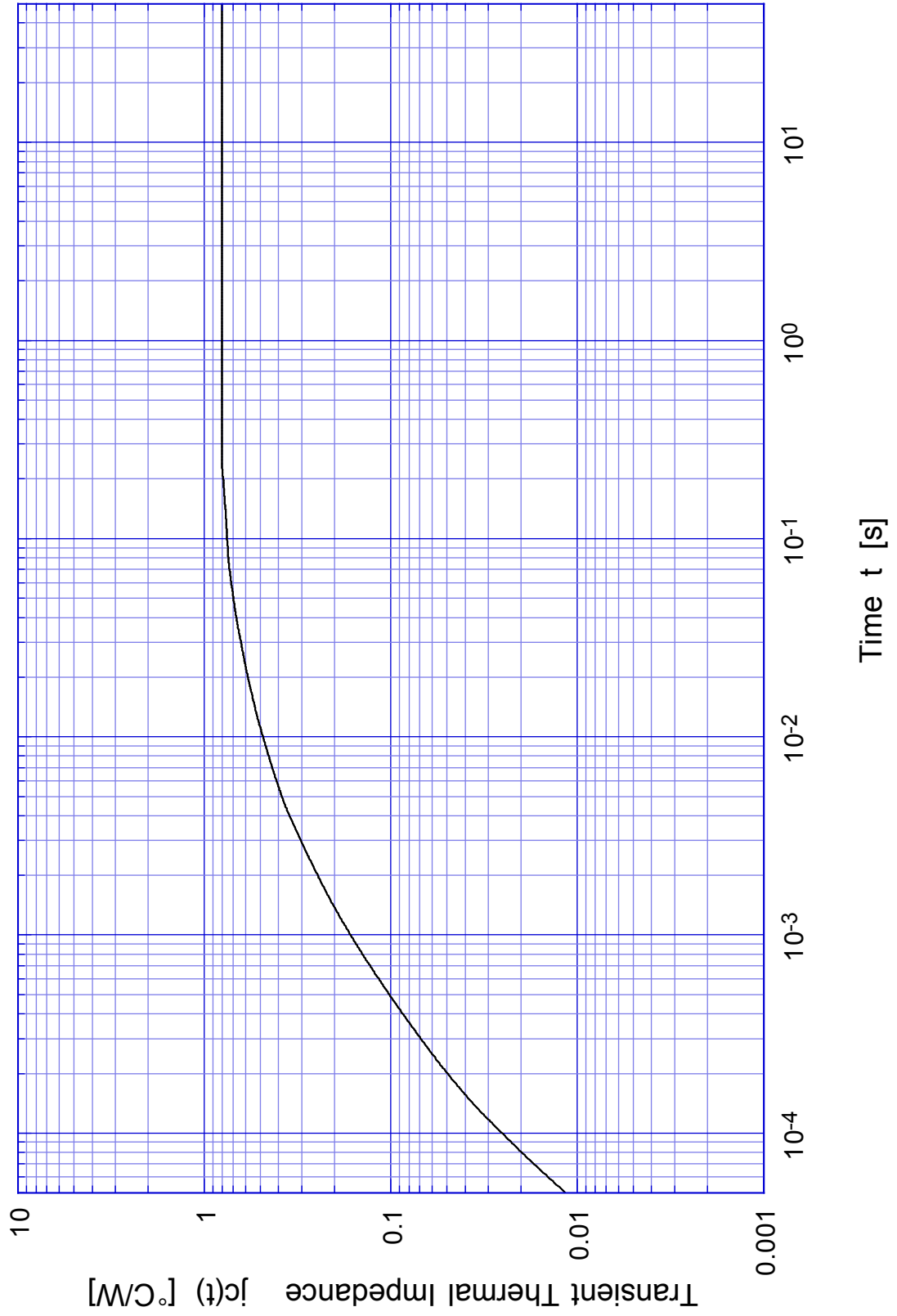
2SC4237 L-Load Switching Time - I_C



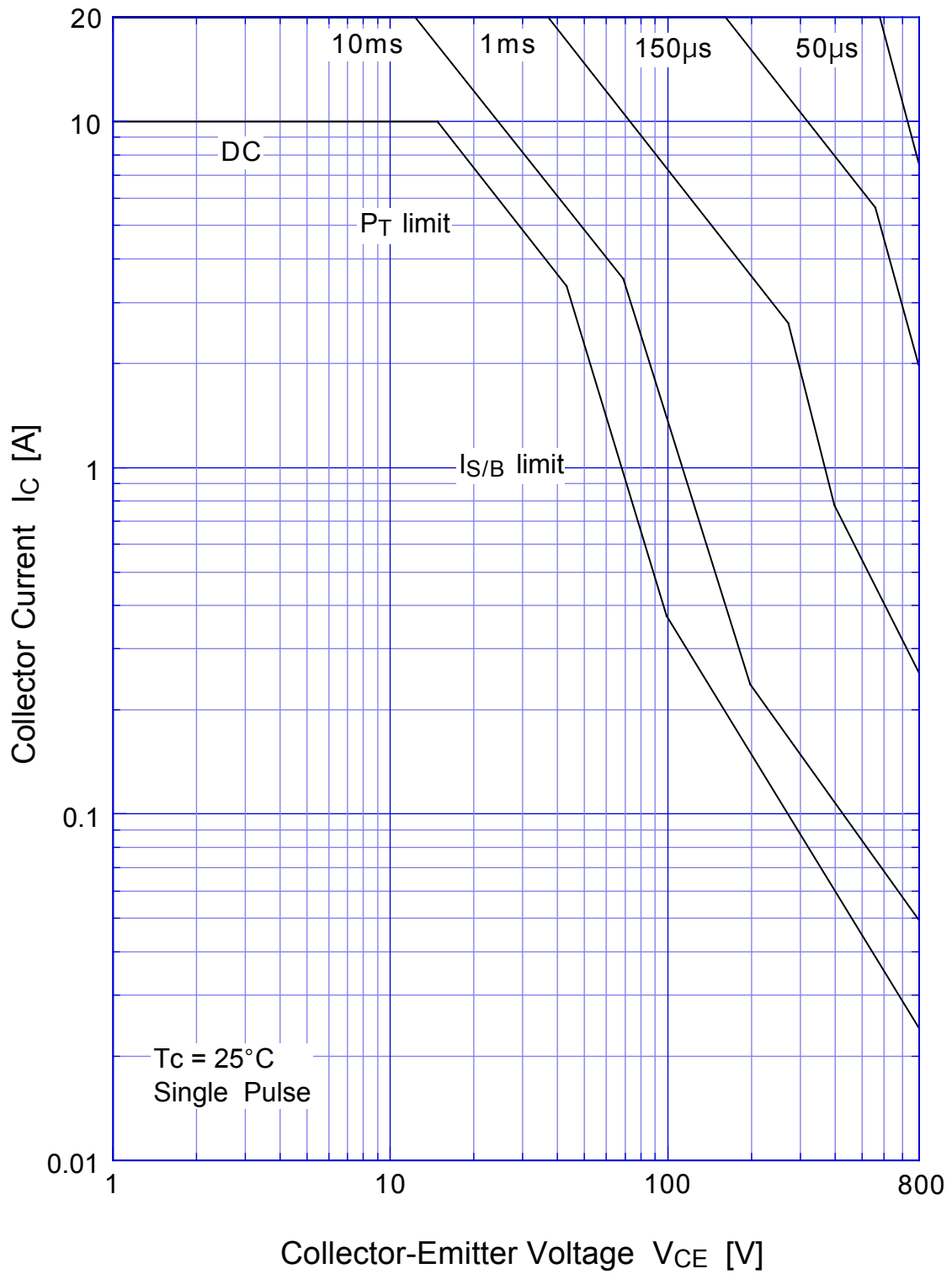
2SC4237 L-Load Switching Time - I_C (At High Temperature)



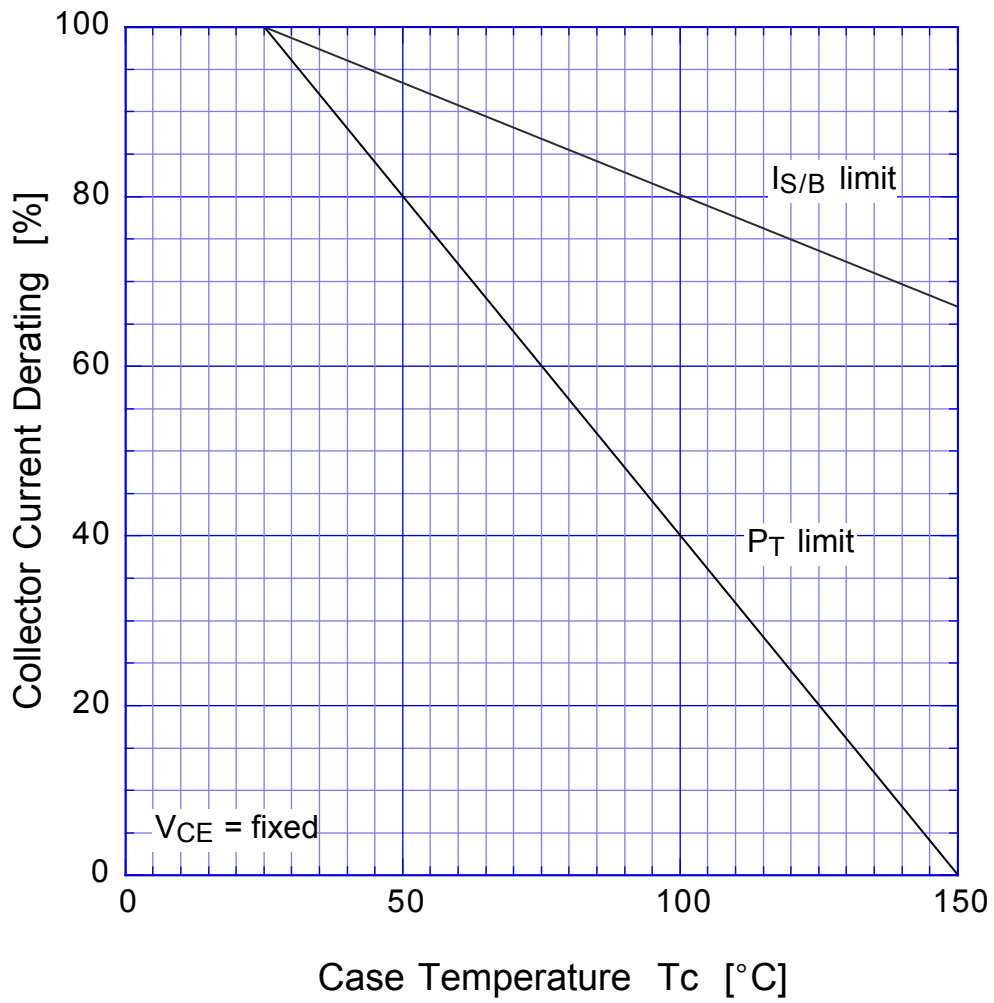
2SC4237 Transient Thermal Impedance



2SC4237 Forward Bias SOA



2SC4237 Collector Current Derating



2SC4237 Reverse Bias SOA

